



# PRODUCT/PROCESS CHANGE NOTIFICATION

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PCN IPG-IPC/14/8789  
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**VIPER16 : Metal mask change**

**Table 1. Change Implementation Schedule**

Forecasted implementation date for change	15-Feb-2015
Forecasted availability date of samples for customer	20-Dec-2014
Forecasted date for <b>STMicroelectronics</b> change Qualification Plan results availability	14-Nov-2014
Estimated date of changed product first shipment	15-Mar-2015

**Table 2. Change Identification**

Product Identification (Product Family/Commercial Product)	See attached
Type of change	Product design change
Reason for change	To improve the device application performance
Description of the change	We have modified the enable logic port of the circuitry error amplifier in order to improve the ESD up to 8 kV and we have increased the UVLO value in order to enhance the performances during the repetitive test for turn-on and turn-off.
Change Product Identification	By a new Finished Goods code
Manufacturing Location(s)	



## DOCUMENT APPROVAL

Name	Function
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**WHAT:**

A metal mask modification has been introduced on the controller UP40, belonging to the MV61 line of the VIPER16 products listed below.

We have modified the enable logic port of the circuitry error amplifier in order to improve the ESD up to 8 kV and we have increased the UVLO value in order to enhance the performances during the repetitive test for turn-on and turn-off.

**WHY:**

The change has been made in order to improve the device application performance.

**HOW:**

Please see the attached Reliability Report.

The new version of the VIPER16 will be identified by a new internal part number (Finished Goods), as follows:

Commercial Product	Package	New Finished Goods
VIPER16HD (tube) VIPER16HDTR (Tape & Reel)	SO 16	VIPER16HD-13/ VIPER16HDTR-13/
VIPER16LD (tube) VIPER16LDTR (Tape & Reel)		VIPER16LD-13/ VIPER16LDTR-13/
VIPER16LN (tube) VIPER16HN (tube)	PDIP 7	VIPER16LN-39/ VIPER16HN-25/

**WHEN:**

The production of the new products is planned to start middle of February 2015, depending on the material availability and customers' volumes. Phase-out and phase-in will be done accordingly.

Samples of the new version will be available from Dec 20<sup>th</sup> onwards.

# Reliability Report

General Information	
<b>Product Line</b>	<i>MV61BE6 (VL8Q6WT+UP40BE5)</i>
<b>Product Description</b>	<i>High Voltage Converter</i>
<b>Product division</b>	<i>I&amp;PC</i>
<b>Package</b>	<i>PDIP7/SO16N</i>
<b>Silicon process technology</b>	<i>BCD6 (UP40) SUPERMESH (VL8Q)</i>

Locations	
<b>Wafer fab location</b>	<i>AMJ9 (VL8Q6WT) + CTM8 (UP40BE5)</i>
<b>Assembly plant location</b>	<i>ST-LONGGANG(CHINA) &amp; UTAC THAI</i>
<b>Reliability assessment</b>	<i>Pass</i>

## DOCUMENT HISTORY

Version	Date	Pages	Author	Comment
1.0	17-Jul-12	7	G. D'Angelo	Original document

Issued by  
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Approved by  
**Alceo Paratore**

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## **1 APPLICABLE AND REFERENCE DOCUMENTS**

<b>Document reference</b>	<b>Short description</b>
<b>AEC-Q100</b>	: Stress test qualification for integrated circuits
<b>8161393A</b>	: General Specification For Product Development



## 2 RELIABILITY EVALUATION OVERVIEW

### 2.1 Objectives

This report contains the reliability evaluation of MV61BE6 (VL8Q6WT+UP40BE5) device diffused in ANG MO KIO AMJ9 (VL8Q6WT) + CTM8 (UP40BE5) and assembled in PDIP7/SO16N in ST-LONGGANG(CHINA) & UTAC THAI.

Considering that UP40BE5 controller is a metal option of UP409BC5 controller, included in the already qualified MV61BCA (see Report RR004011CS2047) only a reduced set of trials has to be performed

According to Reliability Qualification Plan, below is the list of the trials performed:

#### Die Oriented Tests

- High Temperature Reverse Bias

### 2.2 Conclusion

Taking in account the **results of the trials performed** the MV61BE6 (VL8Q6WT+UP40BE5) diffused in ANG MO KIO AMJ9 (VL8Q6WT) + CTM8 (UP40BE5) and assembled in PDIP7 & SO16N in ST-LONGGANG(CHINA) & UTAC THAI **can be qualified** from reliability viewpoint.

## 2.3 Traceability

Wafer fab information UP40	
Wafer fab manufacturing location	CATANIA
Wafer diameter	8 inches
Wafer thickness	375µm
Silicon process technology	BCD6 3M
Die finishing back side	RAW SILICON
Die size	1320x1112µm
Bond pad metallization layers	AlCu
Passivation	USG - SiN - PIX
Metal levels	3

Wafer fab information VL8Q	
Wafer fab manufacturing location	AMJ9
Wafer diameter	6 inches
Wafer thickness	280µm
Silicon process technology	SUPERMESH
Die finishing back side	Ti-Ni-Au
Die size	2650x1290µm
Bond pad metallization layers	AlSi
Passivation	SiN
Metal levels	1

Assembly Information	
Assembly plant location	ST-LONGGANG -CHINA
Package description	PDIP 7
Molding compound	Hysol GR360A-ST
Wires bonding materials/diameters	Au/1mil
Die attach material	Ablestik 8390S

Assembly Information	
Assembly plant location	UTAC Thai Limited
Package description	SO16N
Die pad size	Dual Die Pads 2.83x3.4mm – 1.8x1.8mm
Molding compound	Sumitomo G605
Wires bonding materials/diameters	Au/1mil
Die attach material	Ablebond 8200T
Lead solder material	Ni/Pd/Au PPF

### 3 TESTS RESULTS SUMMARY

#### 3.1 Test plan and results summary

Die Oriented Tests (on PDIP7)							
Test	Method	Conditions	Failure/SS			Duration	Note
			Lot 1(a)	Lot 2(b)	Lot 3(b)		
HTRB	High Temperature Reverse Bias	T <sub>j</sub> =150°C V <sub>drain</sub> =800V, V <sub>dd</sub> =22V	0/77	-	-	168h	

## **4 TESTS DESCRIPTION & DETAILED RESULTS**

### **4.1 Die oriented tests**

#### **4.1.1 High Temperature Reverse Bias**

This test is performed to evaluate die problems related with chip stability, layout structure, surface contamination and oxide faults.

The flow chart is the following:

- Initial testing @ Ta=25°C
- Final Testing @ 168hrs @ Ta=25°C

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